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# N-Channel NexFET™ Power MOSFET

Check for Samples: CSD16327Q3

#### **FEATURES**

- Optimized for 5V Gate Drive
- Ultra Low Qg and Qgd
- Low Thermal Resistance
- Avalanche Rated
- · Pb Free Terminal Plating
- RoHS Compliant
- · Halogen Free
- SON 3.3mm x 3.3mm Plastic Package

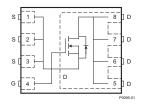
#### **APPLICATIONS**

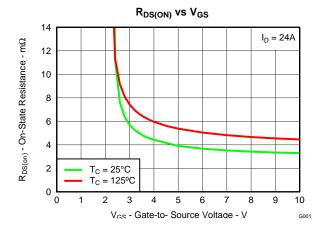
- Point-of-Load Synchronous Buck Converter for Applications in Networking, Telecom and Computing Systems
- Optimized for Control or Synchronous FET Applications

#### **DESCRIPTION**

The NexFET™ power MOSFET has been designed to minimize losses in power conversion and optimized for 5V gate drive applications.







#### PRODUCT SUMMARY

| $V_{DS}$            | Drain to Source Voltage       | 25                       | V   |    |
|---------------------|-------------------------------|--------------------------|-----|----|
| $Q_g$               | Gate Charge Total (4.5V)      | 6.2                      | 6.2 |    |
| $Q_{gd}$            | Gate Charge Gate to Drain     | to Drain 1.1             |     |    |
|                     |                               | $V_{GS} = 3V$            | 5   | mΩ |
| R <sub>DS(on)</sub> | Drain to Source On Resistance | V <sub>GS</sub> = 4.5V 4 |     |    |
|                     |                               | $V_{GS} = 8V$            | 3.4 |    |
| $V_{th}$            | Threshold Voltage             | 1.2                      |     | V  |

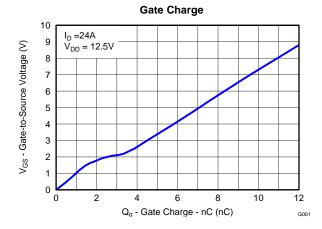
#### ORDERING INFORMATION

| Device     | Package                          | Media           | Qty  | Ship             |  |
|------------|----------------------------------|-----------------|------|------------------|--|
| CSD16327Q3 | SON 3.3 × 3.3<br>Plastic Package | 13-inch<br>reel | 2500 | Tape and<br>Reel |  |

#### **ABSOLUTE MAXIMUM RATINGS**

| T <sub>A</sub> = 2                   | 5°C unless otherwise stated  | VALUE      | UNIT |
|--------------------------------------|--|------------|------|
| $V_{DS}$                             | Drain to Source Voltage  | 25         | V    |
| $V_{GS}$                             | Gate to Source Voltage   | +10 / –8   | ٧    |
|                                      | Continuous Drain Current, T <sub>C</sub> = 25°C                        | 60         | Α    |
| I <sub>D</sub>                       | Continuous Drain Current <sup>(1)</sup>                                | 21         | Α    |
| $I_{DM}$                             | Pulsed Drain Current, T <sub>A</sub> = 25°C <sup>(2)</sup>             | 112        | Α    |
| $P_D$                                | Power Dissipation <sup>(1)</sup>                                       | 3          | W    |
| T <sub>J</sub> ,<br>T <sub>STG</sub> | Operating Junction and Storage<br>Temperature Range                    | -55 to 150 | °C   |
| E <sub>AS</sub>                      | Avalanche Energy, single pulse $I_D = 50A, L = 0.1 mH, R_G = 25\Omega$ | 125        | mJ   |

- (1)  $R_{\theta JA} = 45^{\circ}\text{C/W}$  on  $1\text{in}^2$  Cu (2 oz.) on 0.060" thick FR4 PCB.
- (2) Pulse width ≤300µs, duty cycle ≤2%



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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

#### **ELECTRICAL CHARACTERISTICS**

(T<sub>A</sub> = 25°C unless otherwise stated)

|                     | PARAMETER                        | TEST CONDITIONS   | MIN TYP | MAX  | UNIT |
|---------------------|----------------------------------|---|---------|------|------|
| Static Cl           | naracteristics                   |   |         |      |      |
| BV <sub>DSS</sub>   | Drain to Source Voltage          | $V_{GS} = 0V, I_D = 250\mu A$                           | 25      |      | V    |
| I <sub>DSS</sub>    | Drain to Source Leakage Current  | V <sub>GS</sub> = 0V, V <sub>DS</sub> = 20V             |         | 1    | μΑ   |
| I <sub>GSS</sub>    | Gate to Source Leakage Current   | $V_{DS} = 0V, V_{GS} = +10/-8V$                         |         | 100  | nA   |
| V <sub>GS(th)</sub> | Gate to Source Threshold Voltage | $V_{DS} = V_{GS}, I_D = 250 \mu A$                      | 0.9 1.2 | 1.4  | V    |
|                     |                                  | $V_{GS} = 3V, I_D = 24A$                                | 5       | 6.5  | mΩ   |
| R <sub>DS(on)</sub> | Drain to Source On Resistance    | $V_{GS} = 4.5V, I_D = 24A$                              | 4       | 4.8  |      |
|                     |                                  | $V_{GS} = 8V, I_D = 24A$                                | 3.4     | 4    |      |
| g <sub>fs</sub>     | Transconductance                 | V <sub>DS</sub> = 12.5V, I <sub>D</sub> = 24A           | 96      |      | S    |
| Dynamic             | : Characteristics                |   |         | *    |      |
| C <sub>ISS</sub>    | Input Capacitance                |   | 1020    | 1300 | pF   |
| Coss                | Output Capacitance               | V <sub>GS</sub> = 0V, V <sub>DS</sub> = 12.5V, f = 1MHz | 740     | 960  | pF   |
| C <sub>RSS</sub>    | Reverse Transfer Capacitance     |   | 50      | 65   | pF   |
| Rg                  | Series Gate Resistance           |   | 1.4     | 2.8  | Ω    |
| Qg                  | Gate Charge Total (4.5V)         |   | 6.2     | 8.4  | nC   |
| $Q_{gd}$            | Gate Charge Gate to Drain        |   | 1.1     |      | nC   |
| Q <sub>gs</sub>     | Gate Charge Gate to Source       | $V_{DS} = 12.5V, I_{D} = 24A$                           | 1.8     |      | nC   |
| Qg(th)              | Gate Charge at Vth               |   | 1       |      | nC   |
| Q <sub>OSS</sub>    | Output Charge                    | V <sub>DS</sub> = 12.5V, V <sub>GS</sub> = 0V           | 14      |      | nC   |
| t <sub>d(on)</sub>  | Turn On Delay Time               |   | 5.3     |      | ns   |
| t <sub>r</sub>      | Rise Time                        | $V_{DS} = 12.5V, V_{GS} = 4.5V I_{D} = 24A$             | 15      |      | ns   |
| t <sub>d(off)</sub> | Turn Off Delay Time              | $R_G = 2\Omega$   | 13      |      | ns   |
| t <sub>f</sub>      | Fall Time                        |   | 6.3     |      | ns   |
| Diode Cl            | haracteristics                   |   |         | "    |      |
| V <sub>SD</sub>     | Diode Forward Voltage            | $I_S = 24A, V_{GS} = 0V$                                | 0.85    | 1    | V    |
| Q <sub>rr</sub>     | Reverse Recovery Charge          | $V_{DD} = 12.5V$ , $I_F = 24A$ , $di/dt = 300A/\mu s$   | 21      |      | nC   |
| t <sub>rr</sub>     | Reverse Recovery Time            | $V_{DD} = 12.5V$ , $I_F = 24A$ , $di/dt = 300A/\mu s$   | 16      |      | ns   |

#### THERMAL CHARACTERISTICS

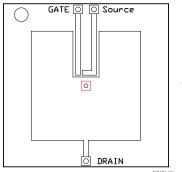
 $(T_{\Delta} = 25^{\circ}C \text{ unless otherwise stated})$ 

| ( · A –           |  |     |     |     |      |
|-------------------|--|-----|-----|-----|------|
|                   | PARAMETER  | MIN | TYP | MAX | UNIT |
| $R_{\theta JC}$   | Thermal Resistance Junction to Case <sup>(1)</sup>       |     |     | 1.7 | °C/W |
| R <sub>A.IA</sub> | Thermal Resistance Junction to Ambient <sup>(1)(2)</sup> |     |     | 56  | °C/W |

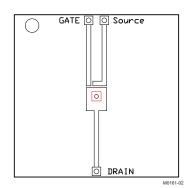
<sup>(1)</sup> RqJC is determined with the device mounted on a 1-inch2 (6.45-cm2), Cu pad on a 1.5-inch × 1.5-inch thick FR4 PCB. RqJC is specified by design, whereas RqJA is determined by the user's board design.

<sup>(2)</sup> Device mounted on FR4 material with 1-inch2 2-oz.Cu.

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Max  $R_{\theta JA} = 56^{\circ} C/W$  when mounted on 1 inch<sup>2</sup> of 2 oz. Cu.



Max  $R_{\theta JA} = 179^{\circ} C/W$  when mounted on minimum pad area of 2 oz. Cu.

#### TYPICAL MOSFET CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$ 

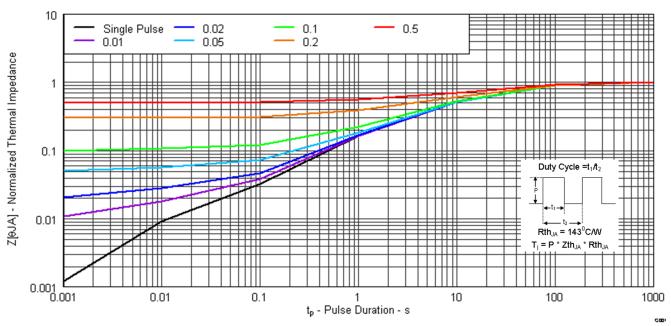


Figure 1. Transient Thermal Impedance

# **ISTRUMENTS**

# **TYPICAL MOSFET CHARACTERISTICS (continued)**

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$ 

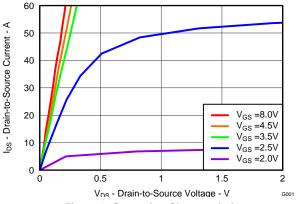


Figure 2. Saturation Characteristics

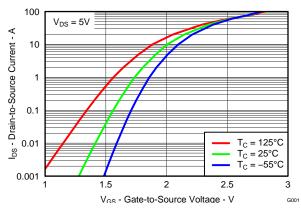


Figure 3. Transfer Characteristics

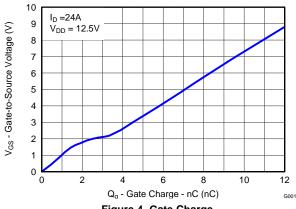


Figure 4. Gate Charge

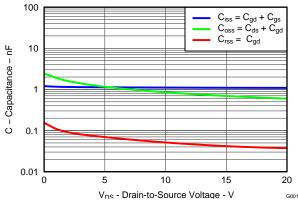


Figure 5. Capacitance

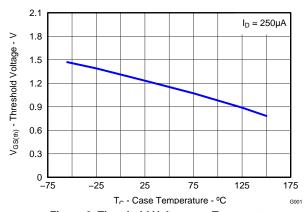


Figure 6. Threshold Voltage vs. Temperature

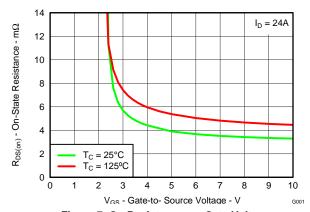


Figure 7. On Resistance vs. Gate Voltage

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# TYPICAL MOSFET CHARACTERISTICS (continued)

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$ 

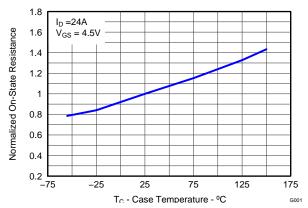


Figure 8. Normalized On Resistance vs. Temperature

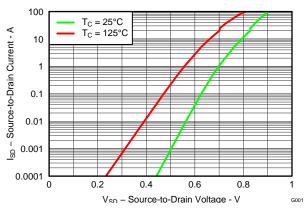


Figure 9. Typical Diode Forward Voltage

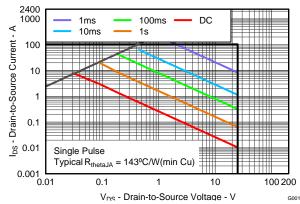


Figure 10. Maximum Safe Operating Area

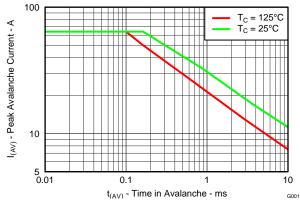
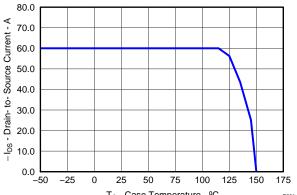


Figure 11. Single Pulse Unclamped Inductive Switching

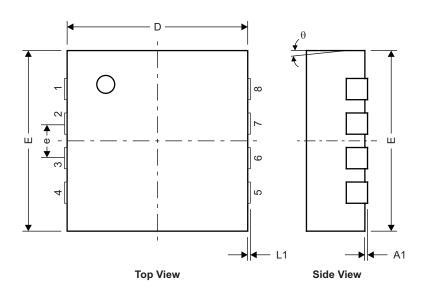


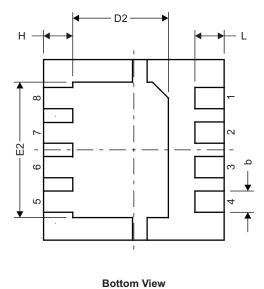
 $$T_{\rm C}$$  - Case Temperature -  ${}^{\rm QC}$  Figure 12. Maximum Drain Current vs. Temperature

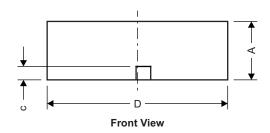


# **MECHANICAL DATA**

# **Q3 Package Dimensions**





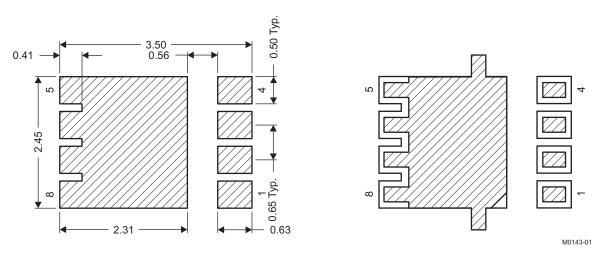


M0142-01

| DIM | l     | MILLIMETERS     | 3     |       | INCHES |       |
|-----|-------|-----------------|-------|-------|--------|-------|
|     | MIN   | NOM             | MAX   | MIN   | NOM    | MAX   |
| Α   | 0.950 | 1.000           | 1.100 | 0.037 | 0.039  | 0.043 |
| A1  | 0.000 | 0.000           | 0.050 | 0.000 | 0.000  | 0.002 |
| b   | 0.280 | 0.340           | 0.400 | 0.011 | 0.013  | 0.016 |
| С   | 0.150 | 0.200           | 0.250 | 0.006 | 0.008  | 0.010 |
| D   | 3.200 | 3.300           | 3.400 | 0.126 | 0.130  | 0.134 |
| D1  | _     | -               | -     | _     | _      | _     |
| D2  | 1.650 | 1.750           | 1.800 | 0.065 | 0.069  | 0.071 |
| E   | 3.200 | 3.300           | 3.400 | 0.126 | 0.130  | 0.134 |
| E1  | _     | -               | -     | _     | -      | _     |
| E2  | 2.350 | 2.450           | 2.550 | 0.093 | 0.096  | 0.100 |
| е   |       | 0.650 TYP 0.026 |       |       |        |       |
| Н   | 0.35  | 0.450           | 0.550 | 0.014 | 0.018  | 0.022 |
| L   | 0.35  | 0.450           | 0.550 | 0.014 | 0.018  | 0.022 |
| L1  | _     | _               | -     | _     | _      | _     |
| θ   | -     | -               | -     | _     | -      | _     |

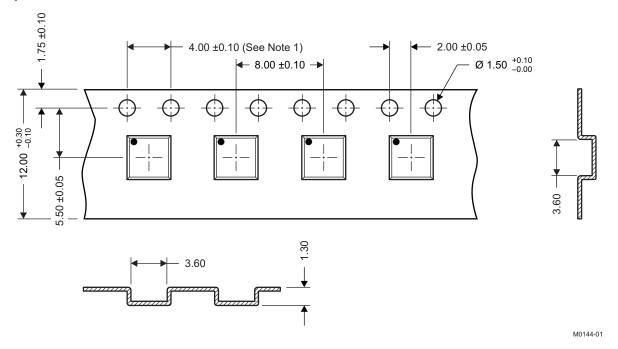
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#### **Recommended PCB Pattern**



For recommended circuit layout for PCB designs, see application note SLPA005 – Reducing Ringing Through PCB Layout Techniques.

# **Q3 Tape and Reel Information**



#### Notes:

- 1. 10 sprocket hole pitch cumulative tolerance ±0.2
- 2. Camber not to exceed 1mm IN 100mm, noncumulative over 250mm
- 3. Material:black static dissipative polystyrene
- 4. All dimensions are in mm (unless otherwise specified)
- 5. Thickness: 0.30 ±0.05mm
- 6. MSL1 260°C (IR and Convection) PbF Reflow Compatible



# PACKAGE OPTION ADDENDUM

11-Apr-2013

#### PACKAGING INFORMATION

| Orderable Device | Status | Package Type | U       | Pins | U    | Eco Plan                 | Lead/Ball Finish | MSL Peak Temp      | Op Temp (°C) | Top-Side Markings | Samples |
|------------------|--------|--------------|---------|------|------|--------------------------|------------------|--------------------|--------------|-------------------|---------|
|                  | (1)    |              | Drawing |      | Qty  | (2)                      |                  | (3)                |              | (4)               |         |
| CSD16327Q3       | ACTIVE | SON          | DQG     | 8    | 2500 | Pb-Free (RoHS<br>Exempt) | CU SN            | Level-1-260C-UNLIM | -55 to 150   | CSD16327          | Samples |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

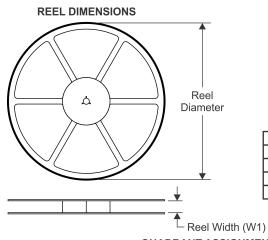
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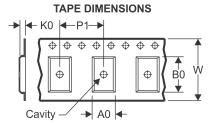
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# PACKAGE MATERIALS INFORMATION

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# TAPE AND REEL INFORMATION





|    | Dimension designed to accommodate the component width     |
|----|---|
| B0 | Dimension designed to accommodate the component length    |
| K0 | Dimension designed to accommodate the component thickness |
| W  | Overall width of the carrier tape                         |
| P1 | Pitch between successive cavity centers                   |

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

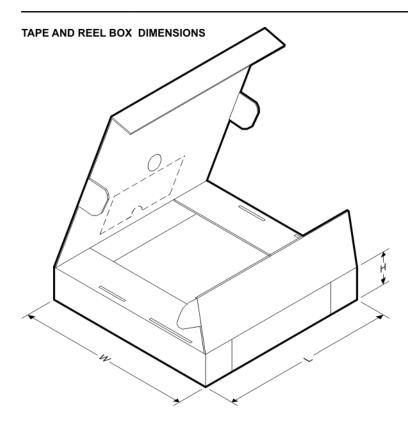


#### \*All dimensions are nominal

| Device     | Package<br>Type | Package<br>Drawing |   |      | Reel<br>Diameter<br>(mm) | Reel<br>Width<br>W1 (mm) | A0<br>(mm) | B0<br>(mm) | K0<br>(mm) | P1<br>(mm) | W<br>(mm) | Pin1<br>Quadrant |
|------------|-----------------|--------------------|---|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| CSD16327Q3 | SON             | DQG                | 8 | 2500 | 330.0                    | 12.8                     | 3.6        | 3.6        | 1.2        | 8.0        | 12.0      | Q1               |

# **PACKAGE MATERIALS INFORMATION**

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#### \*All dimensions are nominal

| Device     | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|------------|--------------|-----------------|------|------|-------------|------------|-------------|
| CSD16327Q3 | SON          | DQG             | 8    | 2500 | 335.0       | 335.0      | 32.0        |

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Products Applications

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OMAP Applications Processors <a href="https://www.ti.com/omap">www.ti.com/omap</a> TI E2E Community <a href="https://example.com/omap">e2e.ti.com/omap</a>

Wireless Connectivity <u>www.ti.com/wirelessconnectivity</u>

# AMEYA360 Components Supply Platform

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# Website:

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# Contact Us:

# > Address:

401 Building No.5, JiuGe Business Center, Lane 2301, Yishan Rd Minhang District, Shanghai , China

# > Sales:

Direct +86 (21) 6401-6692

Email amall@ameya360.com

QQ 800077892

Skype ameyasales1 ameyasales2

# Customer Service :

Email service@ameya360.com

# Partnership :

Tel +86 (21) 64016692-8333

Email mkt@ameya360.com